



MURTA600120R Information



For Reference Only

Part Number MURTA600120R

Manufacturer GeneSiC Semiconductor

Category Discrete Semiconductor Products

Diodes - Rectifiers - Arrays

Description DIODE GEN 1.2KV 300A 3 TOWER

Package Three Tower

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









MURTA600120R Specifications

Manufacturer Part Number	MURTA600120R
Manufacturer	GeneSiC Semiconductor
Category	Discrete Semiconductor Products
	Diodes - Rectifiers - Arrays
Package	Three Tower
Series	-
Diode Configuration	1 Pair Common Anode
Diode Type	Standard
Voltage - DC Reverse (Vr) (Max)	1200V
Current - Average Rectified (Io) (per Diode)	300A
Voltage - Forward (Vf) (Max) @ If	2.6V @ 300A
Speed	Standard Recovery >500ns, > 200mA (Io)
Reverse Recovery Time (trr)	-
Current - Reverse Leakage @ Vr	25μA @ 1200V
Operating Temperature - Junction	-55°C ~ 150°C
Mounting Type	Chassis Mount
Package / Case	Three Tower
Supplier Device Package	Three Tower
	Report errors?

MURTA600120R Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

MURTA600120R Payment Methods





















MURTA600120R Shipping Methods













If you have any question about MURTA600120R, please do not hesitate to contact us!

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